

General Description

The AO8800 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 1.8V while retaining a 12V $V_{GS(MAX)}$ rating. This device is suitable for use as a uni-directional or bi-directional load switch, facilitated by its common-drain configuration.

Features

$$V_{DS} (V) = 30V$$

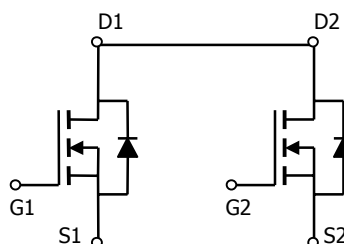
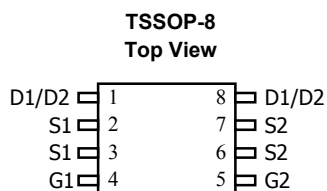
$$I_D = 6.4A$$

$$R_{DS(ON)} < 24m\Omega (V_{GS} = 10V)$$

$$R_{DS(ON)} < 30m\Omega (V_{GS} = 4.5V)$$

$$R_{DS(ON)} < 40m\Omega (V_{GS} = 2.5V)$$

$$R_{DS(ON)} < 70m\Omega (V_{GS} = 1.8V)$$



Absolute Maximum Ratings $T_A=25^\circ C$ unless otherwise noted

| Parameter | Symbol | Maximum | Units |
|----------------------------------------|------------------|------------------|------------|
| Drain-Source Voltage | V_{DS} | 30 | V |
| Gate-Source Voltage | V_{GS} | ± 12 | V |
| Continuous Drain Current ^A | $T_A=25^\circ C$ | 6.4 | A |
| | | $T_A=70^\circ C$ | |
| Pulsed Drain Current ^B | I_{DM} | 30 | |
| Power Dissipation ^A | $T_A=25^\circ C$ | 1.5 | W |
| | | $T_A=70^\circ C$ | |
| Junction and Storage Temperature Range | T_J, T_{STG} | -55 to 150 | $^\circ C$ |

Thermal Characteristics

| Parameter | Symbol | Typ | Max | Units |
|------------------------------------------|-----------------|--------------|-----|--------------|
| Maximum Junction-to-Ambient ^A | $R_{\theta JA}$ | 64 | 83 | $^\circ C/W$ |
| Maximum Junction-to-Ambient ^A | | Steady-State | 89 | |
| Maximum Junction-to-Lead ^C | $R_{\theta JL}$ | 53 | 70 | $^\circ C/W$ |

Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|-----------------------------|---------------------------------------|------------------------------------------------------------------------------------------------------------------------------|-----|------|-----|---------------|
| STATIC PARAMETERS | | | | | | |
| BV_{DSS} | Drain-Source Breakdown Voltage | $I_D=250\mu\text{A}$, $V_{GS}=0\text{V}$ | 30 | | | V |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS}=24\text{V}$, $V_{GS}=0\text{V}$ $T_J=55^\circ\text{C}$ | | | 1 | μA |
| | | | | | 5 | |
| I_{GSS} | Gate-Body leakage current | $V_{DS}=0\text{V}$, $V_{GS}=\pm 12\text{V}$ | | | 100 | nA |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$ | 0.6 | 0.8 | 1 | V |
| $I_{D(ON)}$ | On state drain current | $V_{GS}=4.5\text{V}$, $V_{DS}=5\text{V}$ | 30 | | | A |
| $R_{DS(ON)}$ | Static Drain-Source On-Resistance | $V_{GS}=10\text{V}$, $I_D=6.4\text{A}$ $T_J=125^\circ\text{C}$ | | 20 | 24 | m Ω |
| | | | | 28 | 36 | |
| | | $V_{GS}=4.5\text{V}$, $I_D=6\text{A}$ $V_{GS}=2.5\text{V}$, $I_D=5\text{A}$ $V_{GS}=1.8\text{V}$, $I_D=2.5\text{A}$ | | 23 | 30 | m Ω |
| | | | | 32 | 40 | m Ω |
| g_{FS} | Forward Transconductance | $V_{DS}=5\text{V}$, $I_D=5\text{A}$ | 10 | 17 | | S |
| V_{SD} | Diode Forward Voltage | $I_S=1\text{A}$, $V_{GS}=0\text{V}$ | | 0.66 | 1 | V |
| I_S | Maximum Body-Diode Continuous Current | | | | 2.4 | A |
| DYNAMIC PARAMETERS | | | | | | |
| C_{iss} | Input Capacitance | $V_{GS}=0\text{V}$, $V_{DS}=15\text{V}$, $f=1\text{MHz}$ | | 767 | | pF |
| C_{oss} | Output Capacitance | | | 111 | | pF |
| C_{rss} | Reverse Transfer Capacitance | | | 82 | | pF |
| R_g | Gate resistance | $V_{GS}=0\text{V}$, $V_{DS}=0\text{V}$, $f=1\text{MHz}$ | | 1.3 | | Ω |
| SWITCHING PARAMETERS | | | | | | |
| Q_g | Total Gate Charge | $V_{GS}=4.5\text{V}$, $V_{DS}=15\text{V}$, $I_D=6.4\text{A}$ | | 10 | | nC |
| Q_{gs} | Gate Source Charge | | | 1.2 | | nC |
| Q_{gd} | Gate Drain Charge | | | 3.1 | | nC |
| $t_{D(on)}$ | Turn-On DelayTime | $V_{GS}=10\text{V}$, $V_{DS}=15\text{V}$, $R_L=2.4\Omega$, $R_{GEN}=6\Omega$ | | 5 | | ns |
| t_r | Turn-On Rise Time | | | 5.5 | | ns |
| $t_{D(off)}$ | Turn-Off DelayTime | | | 39 | | ns |
| t_f | Turn-Off Fall Time | | | 4.7 | | ns |
| t_{rr} | Body Diode Reverse Recovery Time | $I_F=5\text{A}$, $dI/dt=100\text{A}/\mu\text{s}$ | | 15 | | ns |
| Q_{rr} | Body Diode Reverse Recovery Charge | $I_F=5\text{A}$, $dI/dt=100\text{A}/\mu\text{s}$ | | 7.1 | | nC |

A: The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^\circ\text{C}$. The value in any a given application depends on the user's specific board design. The current rating is based on the $t \leq 10\text{s}$ thermal resistance rating.

B: Repetitive rating, pulse width limited by junction temperature.

C. The $R_{\theta JA}$ is the sum of the thermal impedance from junction to lead $R_{\theta JL}$ and lead to ambient.

D. The static characteristics in Figures 1 to 6,12,14 are obtained using 80 μs pulses, duty cycle 0.5% max.

E. These tests are performed with the device mounted on 1 in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^\circ\text{C}$. The SOA curve provides a single pulse rating.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

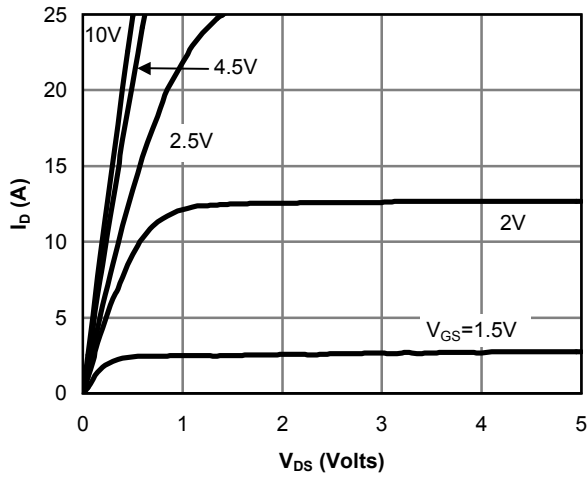


Fig 1: On-Region Characteristics

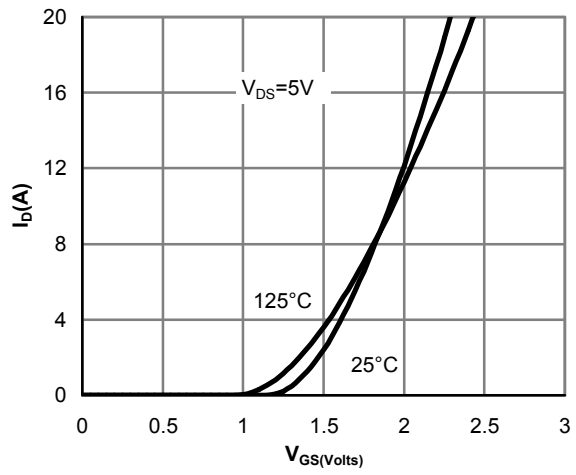


Figure 2: Transfer Characteristics

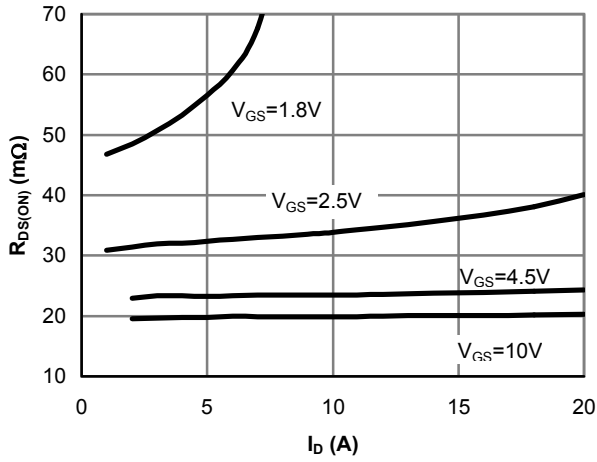


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

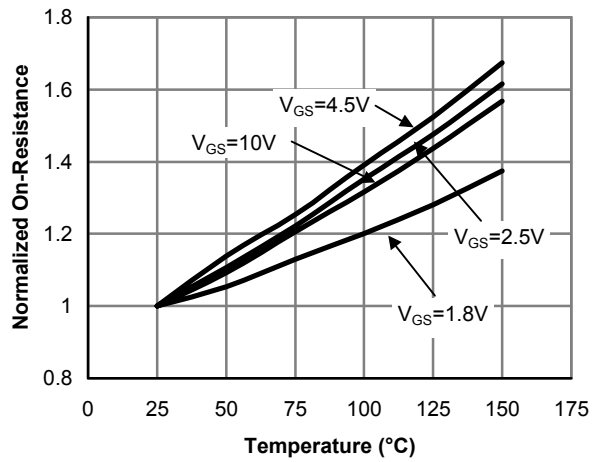


Figure 4: On-Resistance vs. Junction Temperature

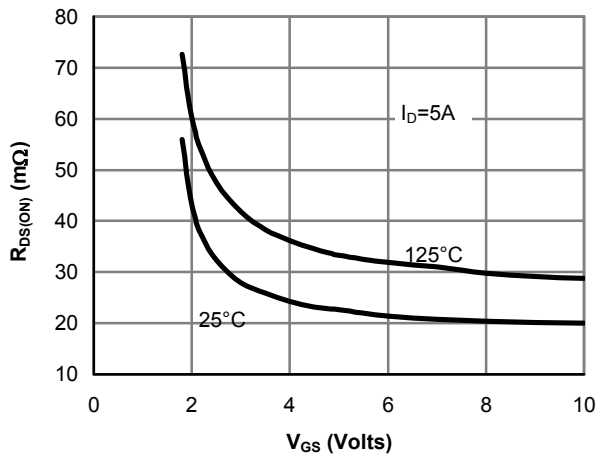


Figure 5: On-Resistance vs. Gate-Source Voltage

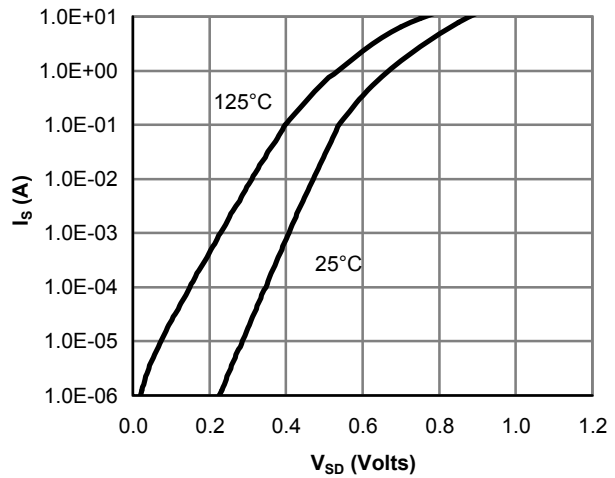


Figure 6: Body-Diode Characteristics

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

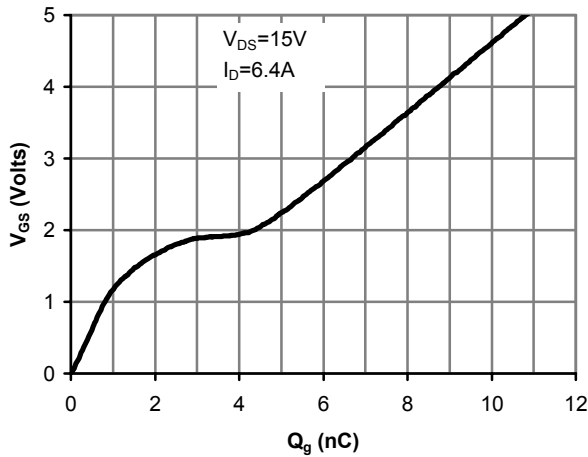


Figure 7: Gate-Charge Characteristics

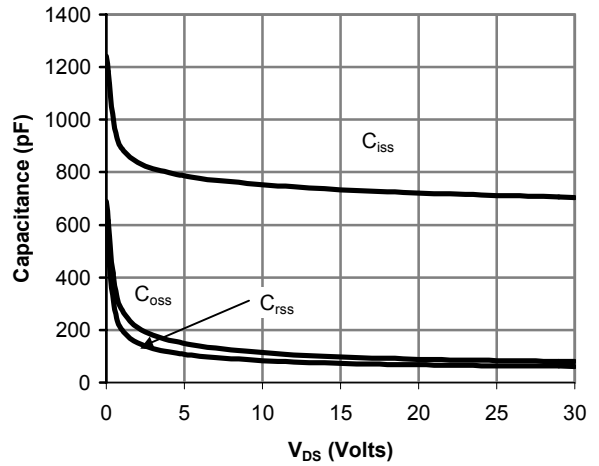


Figure 8: Capacitance Characteristics

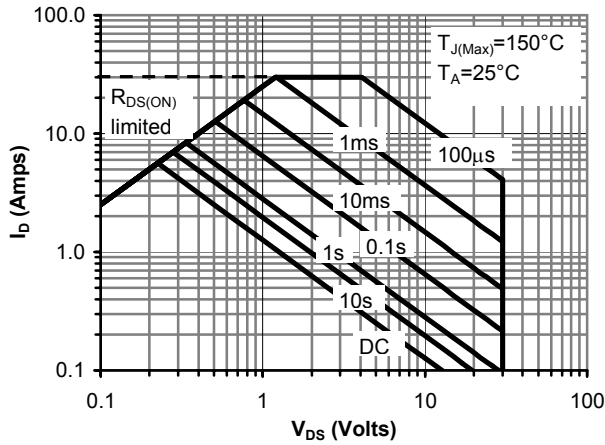


Figure 9: Maximum Forward Biased Safe Operating Area (Note E)

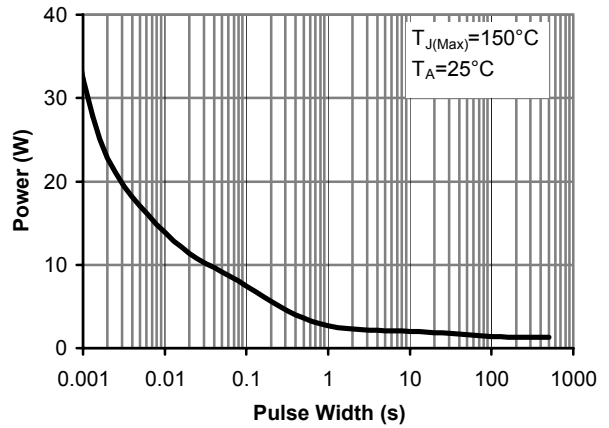


Figure 10: Single Pulse Power Rating Junction-to-Ambient (Note E)

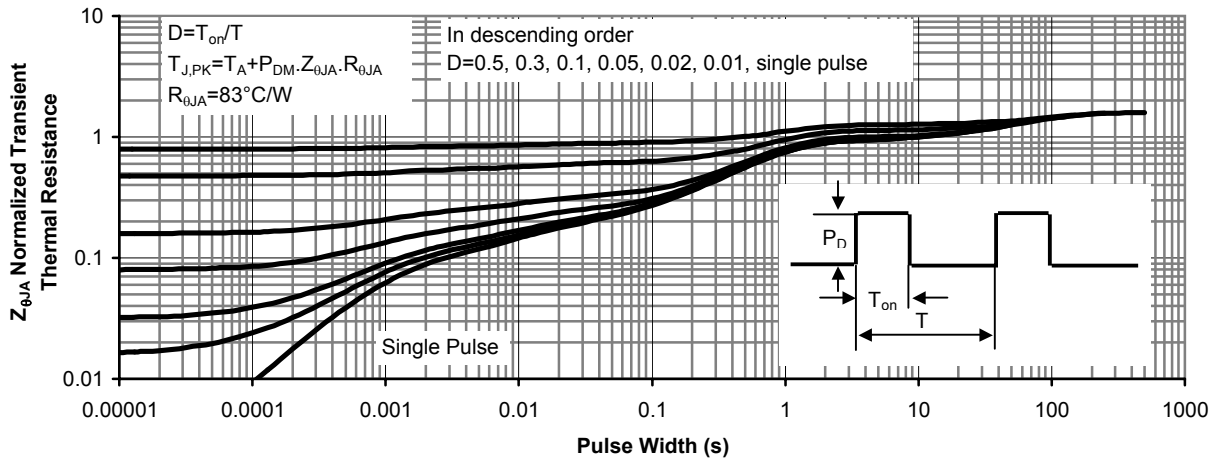
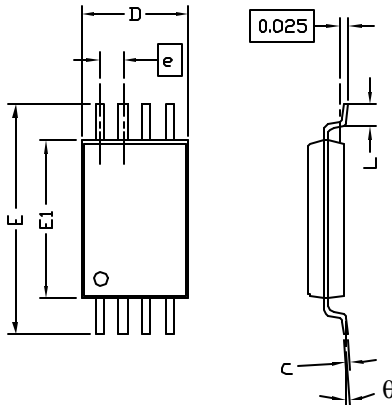
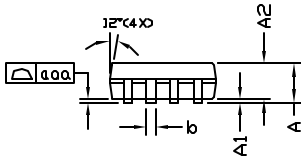


Figure 11: Normalized Maximum Transient Thermal Impedance



| SYMBOLS | DIMENSIONS IN MILLIMETERS | | | DIMENSIONS IN INCHES | | |
|---------|---------------------------|------|------|----------------------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | — | — | 1.20 | — | — | 0.047 |
| A1 | 0.05 | — | 0.15 | 0.002 | — | 0.006 |
| A2 | 0.80 | 1.00 | 1.05 | 0.031 | 0.039 | 0.041 |
| b | 0.19 | — | 0.30 | 0.007 | — | 0.012 |
| c | 0.09 | — | 0.20 | 0.004 | — | 0.008 |
| D | 2.90 | 3.00 | 3.10 | 0.114 | 0.118 | 0.122 |
| E | 6.40 BSC | | | 0.252 BSC | | |
| E1 | 4.30 | 4.40 | 4.50 | 0.169 | 0.173 | 0.177 |
| e | 0.65 BSC | | | 0.0259 (REF) | | |
| L | 0.45 | 0.60 | 0.75 | 0.018 | 0.024 | 0.030 |
| y | — | — | 0.10 | — | — | 0.004 |
| θ | 0° | — | 8° | 0° | — | 8° |



NOTE:
 1. LEAD FINISH: 150 MICRONS (3.8 um) MIN.
 THICKNESS OF Tin/Lead (SOLDER) PLATED ON LEAD
 2. TOLERANCE ±0.100 mm (4 mil) UNLESS OTHERWISE SPECIFIED
 3. COPLANARITY : 0.1000 mm
 4. DIMENSION L IS MEASURED IN GAGE PLANE

PACKAGE MARKING DESCRIPTION

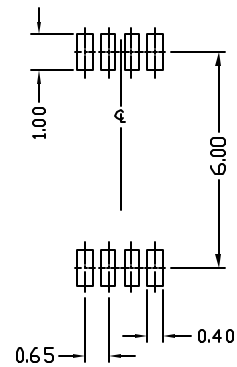


NOTE:
 LG - AOS LOGO
 PARTN - PART NUMBER CODE
 F - FAB LOCATION
 A - ASSEMBLY LOCATION
 W - WEEK CODE
 L.N - ASSEMBLY LOT CODE

TSSOP-8 PART NO. CODE

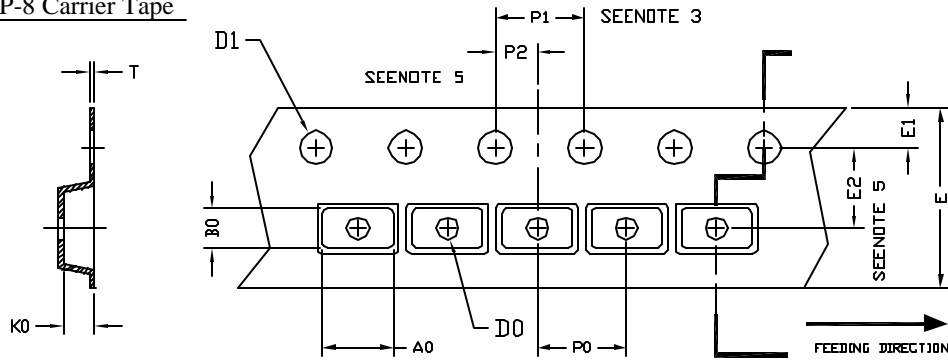
| PART NO. | CODE | PART NO. | CODE | PART NO. | CODE |
|----------|------|----------|------|----------|------|
| AO8800 | 8800 | | | | |
| AO8701 | 8701 | | | | |
| | | | | | |
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| | | | | | |
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RECOMMENDED LAND PATTERN



UNIT: mm

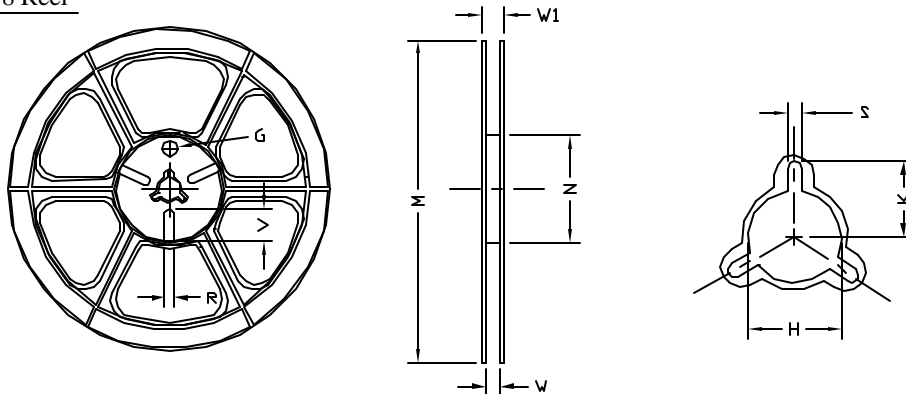
TSSOP-8 Carrier Tape



UNIT: MM

| PACKAGE | A0 | B0 | K0 | D0 | D1 | E | E1 | E2 | P0 | P1 | P2 | T |
|------------------|---------------|---------------|---------------|---------------|--------------|----------------|---------------|---------------|---------------|---------------|---------------|---------------|
| SOP-8 (12 mm) | 6.80 ±0.10 | 3.40 ±0.10 | 1.60 ±0.10 | 1.50 ±0.10 | 1.30 MIN. | 12.00 ±0.30 | 1.75 ±0.10 | 5.50 ±0.05 | 8.00 ±0.10 | 4.00 ±0.10 | 2.00 ±0.10 | 0.30 ±0.05 |

TSSOP-8 Reel



UNIT: MM

| TAPE SIZE | REEL SIZE | M | N | W | W1 | H | K | S | G | R | V |
|-----------|-----------|------------------|-----------------|-------------------------|----------------|-----------------|-------|---------------|-----|-----|-----|
| 12 mm | φ330 | φ178.00 ±0.50 | φ60.00 ±0.50 | 13.00 +1.50 -0.00 | 16.00 ±1.00 | φ13.50 ±0.50 | 10.60 | 2.20 ±0.50 | --- | --- | --- |

TSSOP-8 Tape

Leader / Trailer
& Orientation

